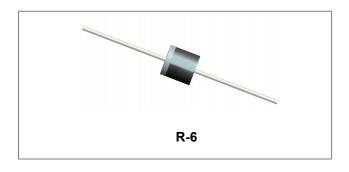






# 30SQ045-1 SCHOTTKY BARRIER RECTIFIER



# **Features**

- Super-high speed & low noise switching
- Low voltage drop
- Terminals finish: Tin Lead-free plated
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

#### **Circuit Diagram**



#### **Applications**

- DC-DC converters
- AC adapter
- · High frequency rectification circuit
- Bypass diodes

#### Maximum Ratings(limiting values, at 25 °C unless otherwise specified)

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	45	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	T <sub>C</sub> = 96°C, In DC	30	Α
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3 ms, half Sine pulse	350	Α

#### **Electrical Characteristics:**

Characteristics	Symbol	Condition		Тур.	Max.	Units
Peak Forward Voltage*	V <sub>FM</sub>	I <sub>FM</sub> =30.0A,Ta=25℃		0.50	0.60	V
Peak Reverse Current*	I <sub>RRM1</sub>	\/ <b>-</b> \/	Ta=25℃	0.10	0.5	mA
	I <sub>RRM2</sub>	$V_{RM}=V_{RRM}$	Ta=100℃	-	50	
Junction Capacitance	Ст	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$		2270	-	pF
Thermal Resistance	R <sub>θJ-c</sub>	Between junction and case		3.0	-	°C/W
	R <sub>θJ-L</sub>	Between junction and lead		2.0	-	

<sup>\*</sup> Pulse width < 300 µs, duty cycle < 2%

- China Germany Korea Singapore United States
  - http://www.smc-diodes.com sales@ smc-diodes.com •



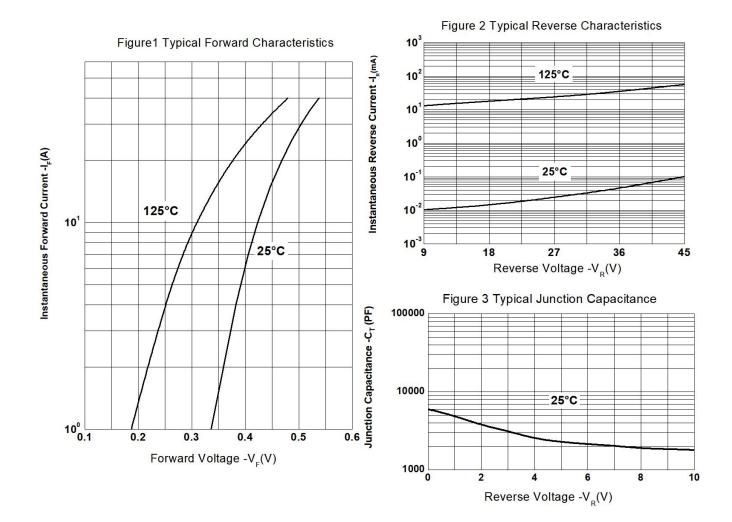




# **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature IN DC Forward Mode, without reverse bias, t ≤1 h	TJ	-	-55 to +200	°C
Storage Temperature	Tstg	-	-55 to +150	°C
Approximate Weight	wt	-	1.9	g
Case Style	R-6			

# **Ratings and Characteristics Curves**



<sup>•</sup> China - Germany - Korea - Singapore - United States •

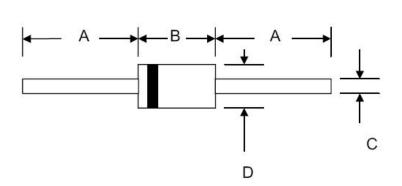
<sup>•</sup> http://www.smc-diodes.com - sales@ smc-diodes.com •







#### **Mechanical Dimensions R-6**



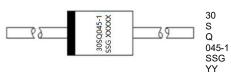
SYMBOL	Millim	neters	hes		
STMBOL	Min.	Max.	Min.	Max.	
А	24.5	-	0.965	-	
В	8.60	9.10	0.340	0.360	
С	1.2	1.3	0.048	0.052	
D	8.60	9.10	0.340	0.360	

# **Ordering Information**

Device	Package	Shipping	
30SQ045-1	R-6(Pb-Free)	500pcs / reel	
30SQ045-1TR	R-6(Pb-Free)	500pcs / reel	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

# **Marking Diagram**



Where XXXXX is YYWWL

= Forward Current (30A) = Package Type = Device Type = Reverse Voltage (45V)

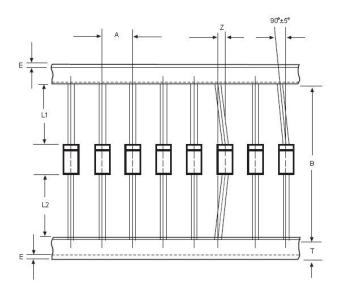
 SSG
 = SSG

 YY
 = Year

 WW
 = Week

 L
 = Lot Number

# **Carrier Tape Specification R-6**



SYMBOL	Millimeters		
	Min.	Max.	
А	9.50	10.50	
В	50.9	53.9	
Z	-	1.20	
Т	5.60	6.40	
Е	-	0.80	
IL1-L2I	-	1.0	

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